

SuperMOS –SOP8 30V V_{DSS} , 9m Ω $R_{DS(ON)}$, N-channel MOSFET

1. Description

The AO4468-ES is N-Channel enhancement MOS Field Effect Transistor. Using advanced shielded gate trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product AO4468-ES is Pb-free.

2. Features

- 30V, $R_{DS(ON)}$ =9m Ω (Typ.) @ V_{GS} =10V
- $R_{DS(ON)}$ =13m Ω (Typ.) @ V_{GS} =4.5V
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

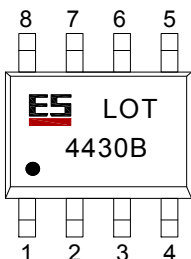
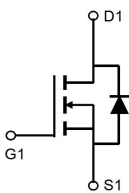
3. Applications

- PWM applications
 - Load switch
 - Power management in portable/desktop PCs
 - DC/DC conversion
- 100% UIS TESTED**

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per Tube	Flammability Rating	Reel size
AO4468-ES	SOP8	4430B/LOT	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	13 inches

5. Pin Configuration and Functions

Pin	Function	Outline	Circuit Diagram
4	Gate		
1/2/3	Source		
5/6/7/8	Drain		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	BV_{DSS}	30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	$T_A=25^{\circ}C$	12
		$T_A=100^{\circ}C$	8
Maximum Power Dissipation	P_D	3.1	W
Pulsed Drain Current	I_{DM}	48	A
Single Pulsed Avalanche Energy ^a	E_{AS}	36	mJ
Operating Junction Temperature	T_J	150	°C
Lead Temperature	T_L	260	°C
Storage Temperature Range	T_{stg}	-55 to 150	°C

Thermal resistance ratings

Single Operation				
Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$		40	°C/W

Notes: a. EAS condition: Starting $T_J=25^{\circ}C$, $V_{DD}=15V$, $V_G=10V$, $R_G=25\Omega$, $L=0.5mH$, $I_{AS}=12A$

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	1.0	1.5	2.2	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=10A$		9	11	m Ω
		$V_{GS}=4.5V, I_D=5A$		13	16	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C_{ISS}	$V_{GS}=0V, f=1MHz, V_{DS}=15V$		1060		pF
Output Capacitance	C_{OSS}			122		
Reverse Transfer Capacitance	C_{RSS}			102		
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS}=10V, V_{DS}=15V, I_D=10A$		21		nC
Gate-to-Source Charge	Q_{GS}			3		
Gate-to-Drain Charge	Q_{GD}			5		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=10V, V_{DS}=15V, I_D=10A, R_G=3\Omega$		4		ns
Rise Time	t_r			2		
Turn-Off Delay Time	$t_{d(OFF)}$			13		
Fall Time	t_f			7		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=10A$			1.5	V

8. Typical Characteristics

Figure 1: Output Characteristics

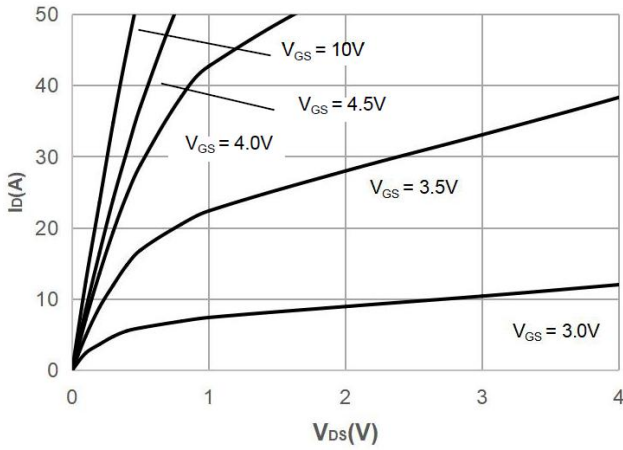


Figure 2: Typical Transfer Characteristics

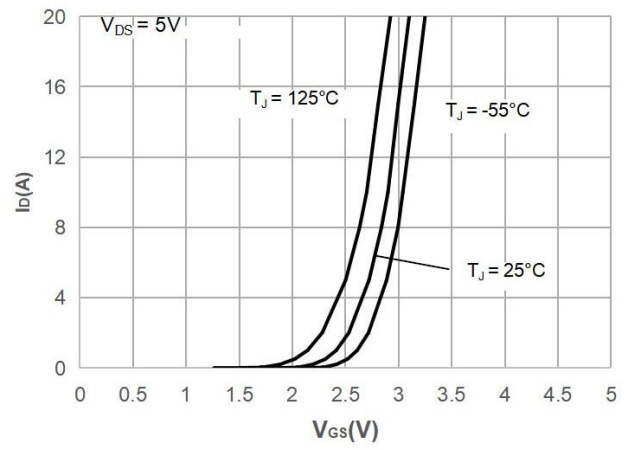


Figure 3: On-resistance vs. Drain Current

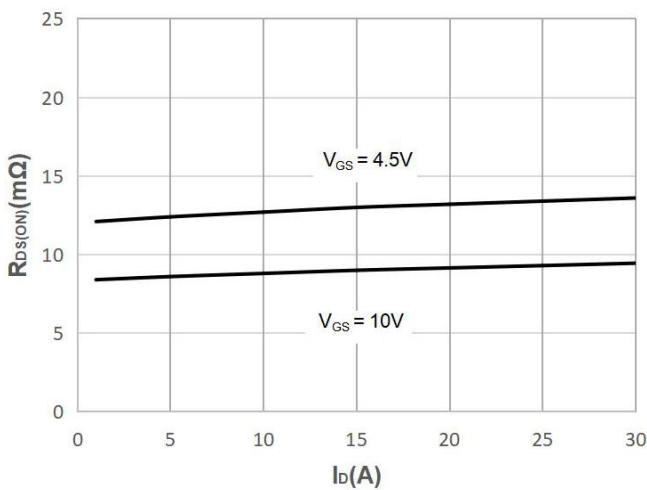


Figure 4: Body Diode Characteristics

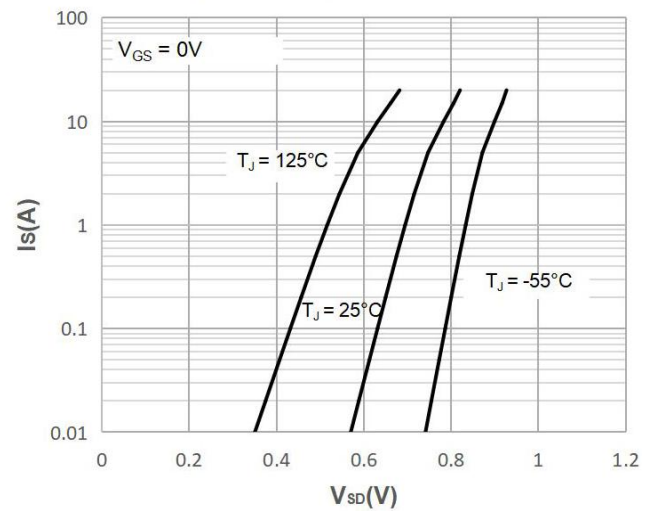


Figure 5: Gate Charge Characteristics

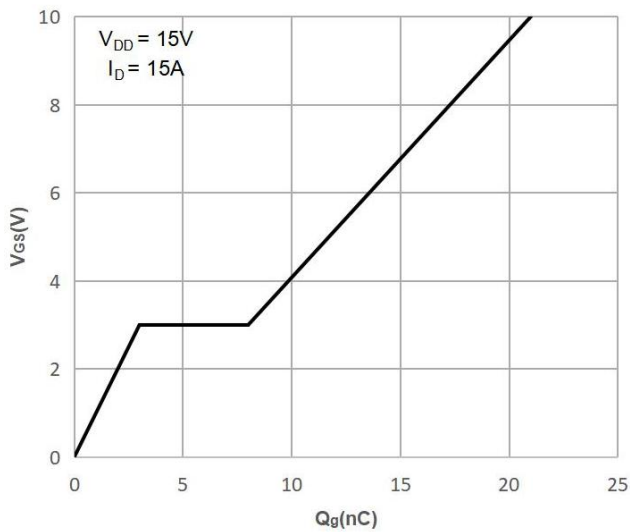


Figure 6: Capacitance Characteristics

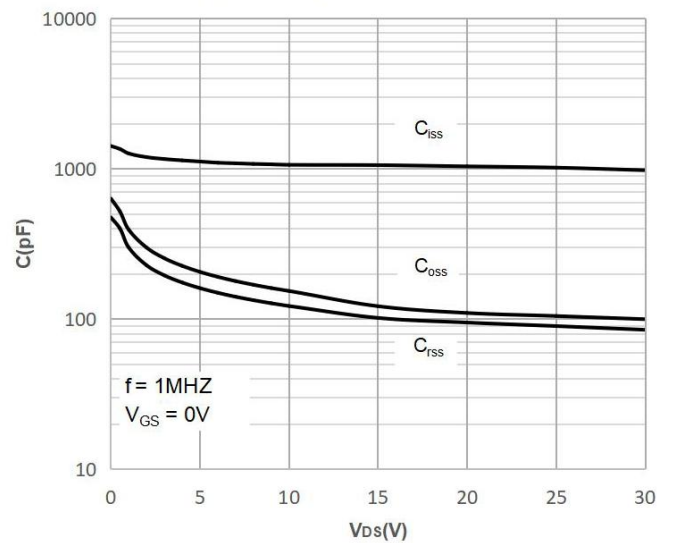


Figure 7: Normalized Breakdown voltage vs. Junction Temperature

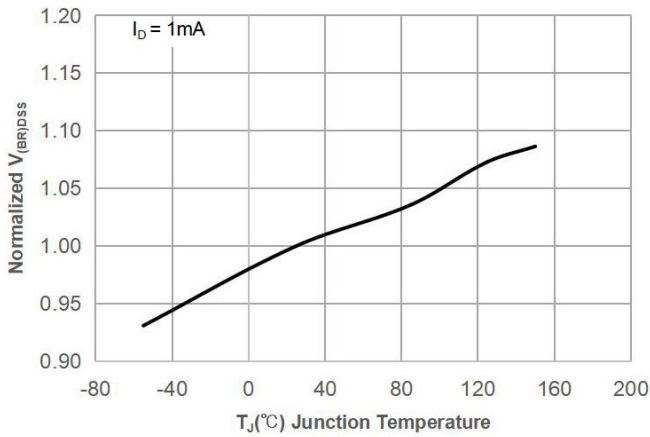


Figure 8: Normalized on Resistance vs. Junction Temperature

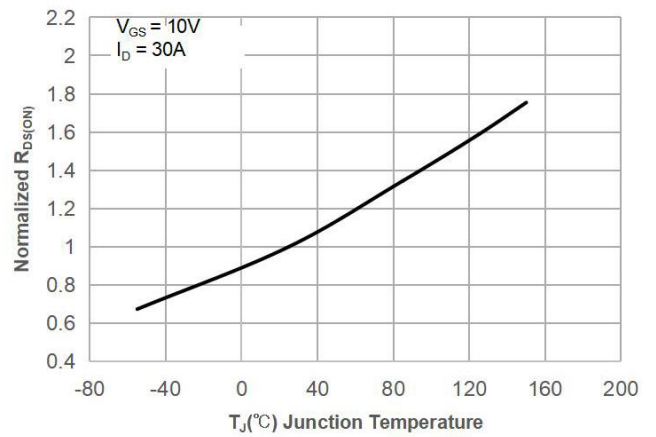


Figure 9: Maximum Safe Operating Area

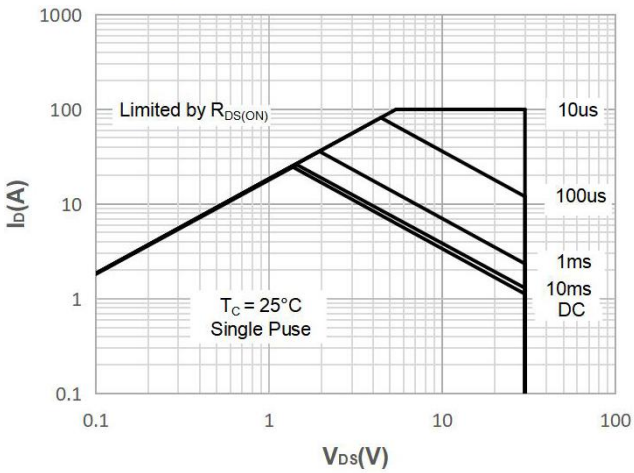


Figure 10: Maximum Continuous Drian Current vs. Case Temperature

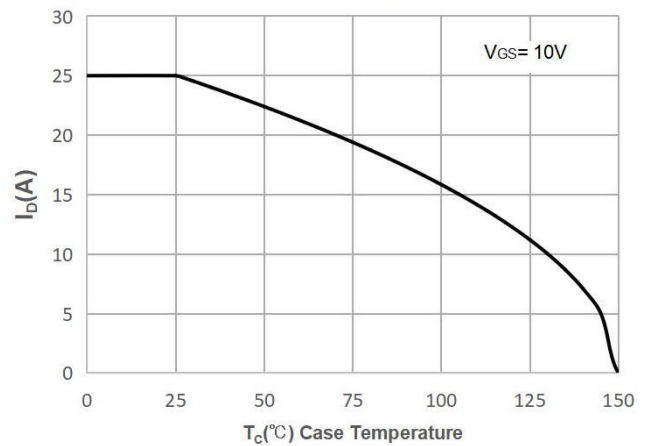


Figure 11: Normalized Maximum Transient Thermal Impedance

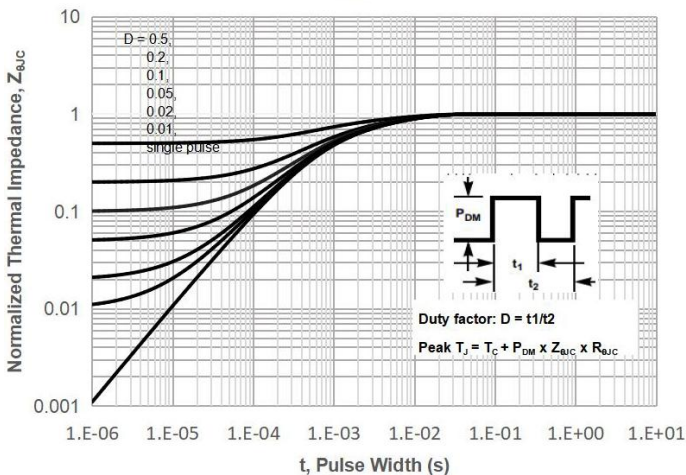
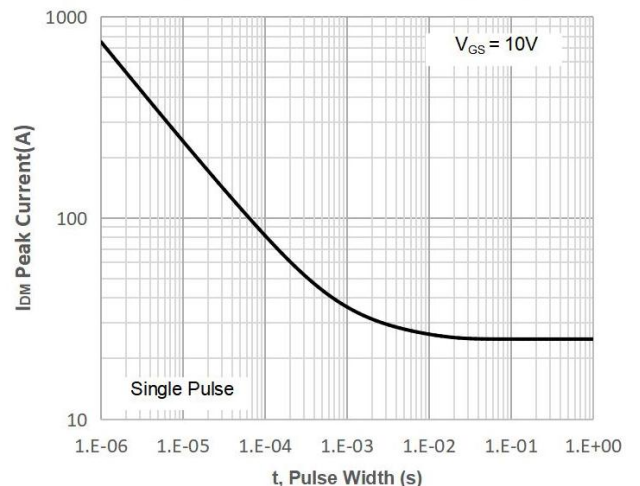
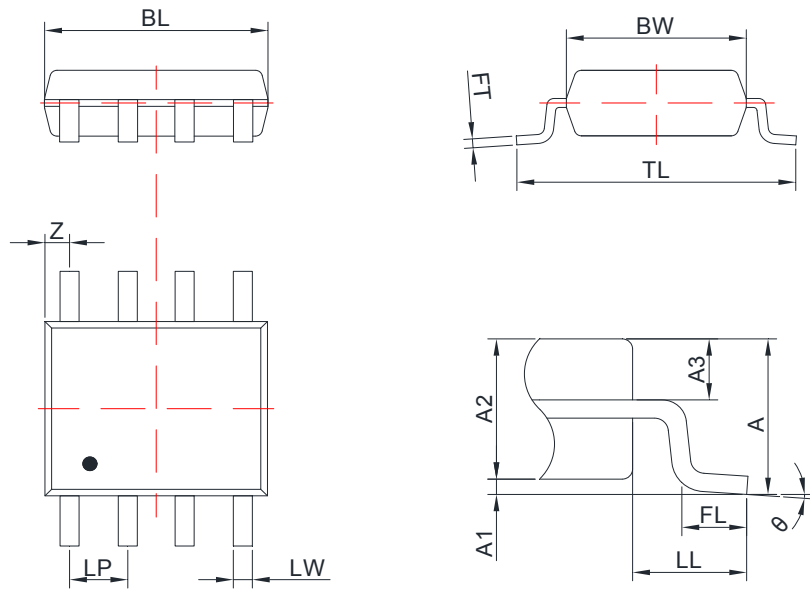


Figure 12: Peak Current Capacity



9. Dimension (SOP8)



COMMON DIMENSIONS: UNITS OF MEASURE=MILLIMETER

Symbol	Dimensions		Symbol	Dimensions	
	Min.	Max.		Min.	Max.
A	1.75		FL	0.50	0.80
A1	0.05	0.15	LP	1.25	1.30
A2	1.40	1.50	LL	1.1 BSC	
A3	0.623 BSC		LW	0.38	0.43
BL	4.80	5.00	TL	5.90	6.10
BW	3.70	4.10	Z	0.54 REF	
FT	0.20	0.21	θ	0°	8°

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